VS-VSKJS203/100

Vishay Semiconductors





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AAP Gen 7 (TO-240AA)

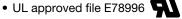
| PRIMARY CHARACTERISTICS | | | | |
|-------------------------|-------------------------|--|--|--|
| I _{F(AV)} | 200 A | | | |
| V _R | 100 V | | | |
| Package | AAP Gen 7 (TO-240AA) | | | |
| Circuit configuration | Two diodes common anode | | | |

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance



- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>
- · Designed and qualified for industrial level

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKJS203.. Schottky rectifier common anode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | |
|-----------------------------------|---|-------------|-------|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | |
| I _{F(AV)} | Rectangular waveform | 200 | А | |
| V _{RRM} | | 100 | V | |
| I _{FSM} | t _p = 5 μs sine | 12 800 | А | |
| V _F | 100 A _{pk} , T _J = 125 °C | 0.87 | V | |
| Тј | Range | -55 to +175 | °C | |

| VOLTAGE RATINGS | | | | |
|--------------------------------------|------------------|-----------------|-------|--|
| PARAMETER | SYMBOL | VS-VSKJS203/100 | UNITS | |
| Maximum DC reverse voltage | V _R | 100 | V | |
| Maximum working peak reverse voltage | V _{RWM} | 100 | v | |



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1

VS-VSKJS203/100



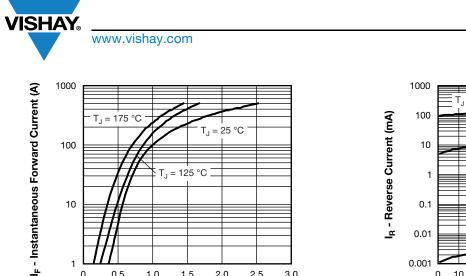
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| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--------------------------------|------------|-------------------------------|---|-------------------------|--------|-------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum average | per module | | V_0 50 % duty cycle at T _C = 121 °C, rectangular waveform | | 200 | |
| forward current | per leg | I _{F(AV)} | | | 100 | |
| Maximum peak one cycle | | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with | 12 800 | A | |
| non-repetitive surge current | | I _{FSM} | 10 ms sine or 6 ms rect. pulse | rated V_{RRM} applied | 1700 | |
| Non-repetitive avalanche energ | у | E _{AS} | $T_J = 25 \text{ °C}, I_{AS} = 5.5 \text{ A}, L = 1 \text{ mH}$ 15 | | mJ | |
| Repetitive avalanche current | | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 1 | | А | |

| ELECTRICAL SPECIFICATIONS | | | | | |
|---------------------------------|------------------|--|---------------------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| | V _{FM} | 100 A | T.I = 25 °C | 0.99 | V |
| | | 200 A | 1j=25 C | 1.34 | |
| Maximum forward voltage drop | | 100 A | T _J = 125 °C | 0.87 | |
| | | 200 A | | 1.09 | |
| Maximum reverse leakage current | I _{RM} | $T_J = 25 \ ^{\circ}C$ | V _R = Rated V _R | 3 | mA |
| Maximum reverse leakage current | | T _J = 125 °C | | 65 | IIIA |
| Maximum junction capacitance | CT | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C | | 2750 | pF |
| Typical series inductance | Ls | Measured lead to lead 5 mm from package body | | 7.0 | nH |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs |
| Maximum RMS insulation voltage | V _{INS} | 50 Hz 3000 (1 min) 3600 (1 s) | | V | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | |
|---|-------------|-----------------------------------|--|-------------|----------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and storage temperature range |) | T _J , T _{Stg} | | -55 to +175 | °C |
| Maximum thermal resistance, junction to case per leg | | R _{thJC} | DC operation | 0.52 | °C/W |
| Typical thermal resistance, case to heatsink per module | | R _{thCS} | | 0.1 | 0/11 |
| Approximate weight | | | | 75 | g |
| Approximate weight | | | | 2.7 | oz. |
| Mounting torque ± 10 % | to heatsink | | A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the | 4 | Nm |
| o 1 | busbar | | spread of the compound. | 3 | INIT |
| Case style | | | JEDEC® | TO-240AA co | mpatible |



T_J = 125 °C

1.5

V_{FM} - Forward Voltage Drop (V)

2.0

2.5

3.0

10

1 0

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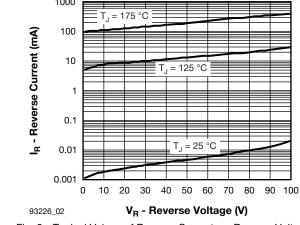
0.5

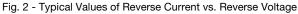
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Fig. 1 - Maximum Forward Voltage Drop Characteristics

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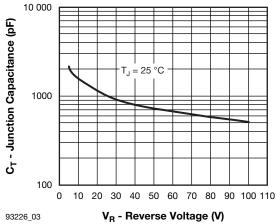


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

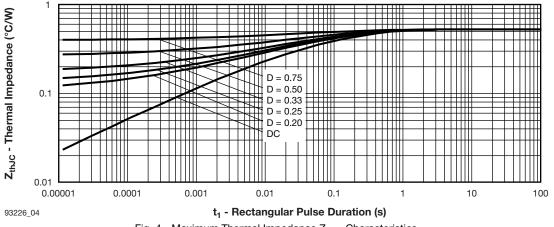
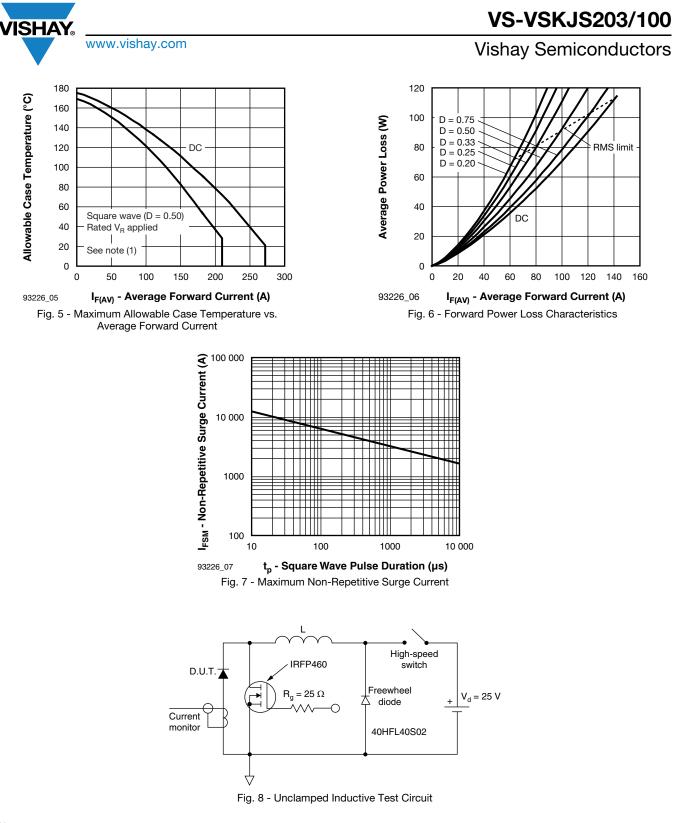


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 D)$; I_R at V_{R1} = 80 % rated V_R

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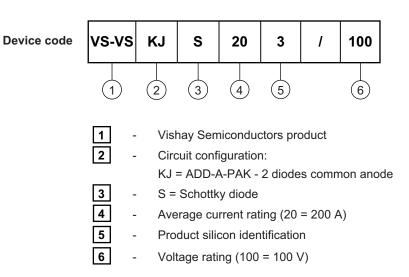
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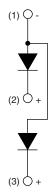
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ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



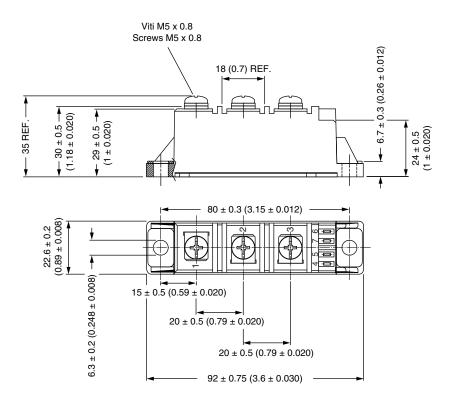
| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|--------------------------|--|--|--|
| Dimensions | www.vishay.com/doc?95369 | | | |

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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